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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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# 2SK2211

#### Silicon N-channel MOSFET

#### For switching circuits

#### ■ Features

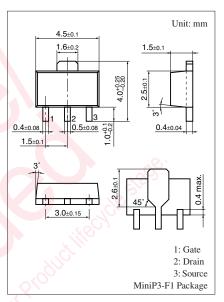
- Low ON resistance
- · High-speed switching
- Mini type package, allowing downsizing of the sets and automatic insertion through the magazine packing

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Drain-source surrender voltage	$V_{\rm DSS}$	30	V
Gate-source surrender voltage	V <sub>GSS</sub>	±20	V
Drain current	$I_D$	1.0	A
Peak drain current	$I_{DP}$	2.0	A
Power dissipation *	$P_{\mathrm{D}}$	1.0	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

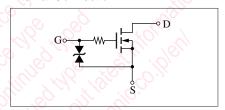
Note) \*: PC board: Copper foil of the drain portion should have a area of 1 cm<sup>2</sup> or more and the board thickness should be 1.7 mm.

P<sub>C</sub> absolute maximum rating without a heat shink: 0.5 W



Marking Symbol: 2M

#### Internal Connection



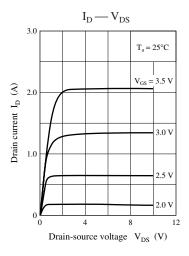
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

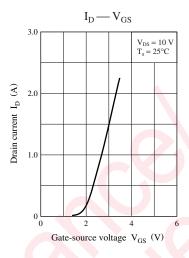
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	$V_{\rm DSS}$	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	30			V
Gate-source surrender voltage	V <sub>GSS</sub>	$I_{GS} = 0.1 \text{ mA}, V_{DS} = 0$	±20			V
Drain-source cutoff current	$I_{DSS}$	$V_{DS} = 25 \text{ V}, V_{GS} = 0$			10	μΑ
Gate-source cutoff current	$I_{GSS}$	$V_{GS} = \pm 15 \text{ V}, V_{DS} = 0$			±10	μΑ
Gate threshold voltage	$V_{th}$	$V_{DS} = 5 \text{ V}, I_D = 1 \text{ mA}$	0.8		2.0	V
Forward transfer admittance *	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, I_{D} = 0.5 \text{ A}$	0.5			S
Drain-source ON resistance *	R <sub>DS(on)1</sub>	$V_{GS} = 4 \text{ V}, I_D = 0.5 \text{ A}$		0.48	0.75	Ω
	R <sub>DS(on)2</sub>	$V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$		0.35	0.60	
Short-circuit forward transfer capacitance (Common source)	C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		87		pF
Short-circuit output capacitance (Common source)	C <sub>oss</sub>			69		pF
Reverse transfer capacitance (Common source)	C <sub>rss</sub>			23		pF
Turn-on delay time	t <sub>d(on)</sub>	$V_{GS} = 10 \text{ V}, V_{DD} = 10 \text{ V}, I_D = 0.5 \text{ A},$		12		ns
Fall time	t <sub>f</sub>	$R_L = 20 \Omega$		160		ns
Turn-off delay time	$t_{d(off)}$			60		ns

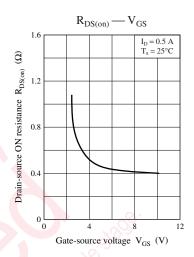
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

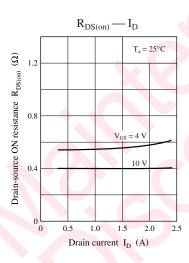
2. \*: Pulse measurement

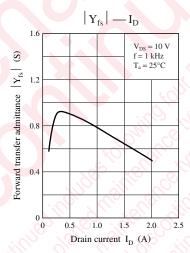
## **Panasonic**

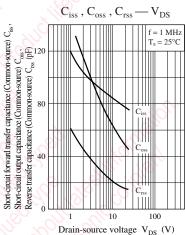












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